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PATENT

**AP20 Rec'd PCT/PTO 31 MAY 2006**

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

**In re application of:**

Larry C. Olsen et al.

**Application No.** Not yet assigned

**Filed:** Herewith

**Confirmation No.** Not yet assigned

**For:** THERMOELECTRIC DEVICES AND  
APPLICATIONS FOR THE SAME

**Examiner:** Not yet assigned

**Art Unit:** Not yet assigned

**Attorney Reference No.** 23-65037-09

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**INFORMATION DISCLOSURE STATEMENT**  
**PURSUANT TO 37 C.F.R. § 1.97(b)(2)**

Listed on the accompanying form PTO-1449 and enclosed herewith are several English-language and/or non-English-language documents. Applicants respectfully request that these documents be listed as references cited on the issued patent.

Copies of United States patents and United States published patent applications do not have to be provided to the Patent Office (37 C.F.R. 1.98(a)(2)(ii)). Copies of unpublished U.S. applications do not have to be provided, as long as the application is available on PAIR, as this requirement of 37 C.F.R. § 1.98(a)(2)(iii) has been waived by the United States Patent and Trademark Office pursuant to the Official Gazette Notice on October 19, 2004 (1287 OG 163). Applicants will provide copies of such patents or applications upon request.

Applicants filed this Information Disclosure Statement ("IDS") within three months of the date of entry of the national stage as set forth in § 1.491 in an international application. As a result, no fee should be required to file this IDS. However, if the Patent Office determines that a fee is required for Applicants to file this IDS, please charge any such fees, or credit overpayment, to Deposit Account No. 02-4550.

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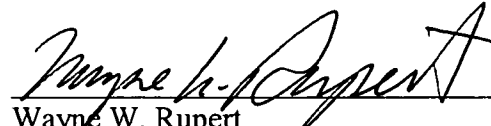
PATENT

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The filing of this IDS shall not be construed to be an admission that the information cited in the statement is, or is considered to be, prior art or otherwise material to patentability as defined in 37 C.F.R. §1.56.

Respectfully submitted,

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Application Number	Not yet assigned
Filing Date	Herewith 01/28/2024
First Named Inventor	Larry C. Olsen
Art Unit	Not yet assigned
Examiner Name	Not yet assigned

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ALL REFERENCES CONSIDERED EXCEPT WHERE LINED THROUGH. /S.G./

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1AP20 Rec'd PCT/PTO 1281 MAY 31 2006 1795  
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<b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b>	Attorney Docket Number	23-65037-09
	Application Number	Not yet assigned
	Filing Date	Here with 12/28/2001 1281
	First Named Inventor	Larry C. Olsen
	Art Unit	Not yet assigned
	Examiner Name	Not yet assigned

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Express Mail No. EV668295874US**INFORMATION DISCLOSURE STATEMENT  
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Application Number	Not yet assigned
Filing Date	Herewith 05/31/2006
First Named Inventor	Larry C. Olsen
Art Unit	Not yet assigned
Examiner Name	Not yet assigned

Examiner's Initials*	Cite No. (optional)	OTHER DOCUMENTS
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First Named Inventor	Larry C. Olsen
Art Unit	Not yet assigned
Examiner Name	Not yet assigned

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